

# **NXV65UP** 20 V, P-channel Trench MOSFET 19 October 2020

**Product data sheet** 

### 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Low threshold voltage
- Very fast switching
- Trench MOSFET technology

### 3. Applications

- Relay driver
- High-speed line driver
- High-side load switch
- Switching circuits

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-20	V
V <sub>GS</sub>	gate-source voltage			-8	-	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-	-2.1	А
Static chara	acteristics						
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -2.1 A; T <sub>j</sub> = 25 °C		-	55	70	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



### 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain		G (17aaa257

### 6. Ordering information

#### Table 3. Ordering information

Type number			
	Name	Description	Version
NXV65UP		plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23

### 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
NXV65UP	%5L

[1] % = placeholder for manufacturing site code

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

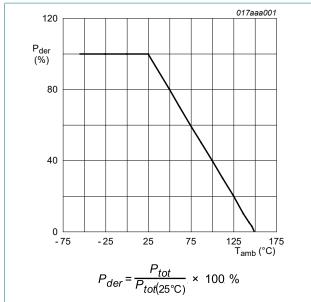
Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-20	V
V <sub>GS</sub>	gate-source voltage			-8	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-2.1	A
		V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	-1.3	A
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-8.4	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	340	mW
			[1]	-	480	mW
		T <sub>sp</sub> = 25 °C		-	2.1	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	n diode					
ls	source current	T <sub>amb</sub> = 25 °C	[1]	-	-0.4	А

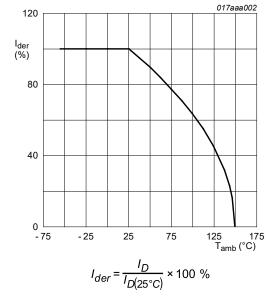
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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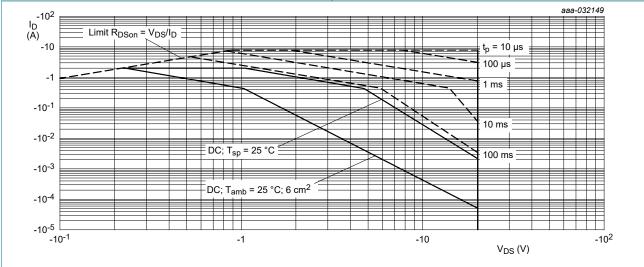


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drainsource voltage

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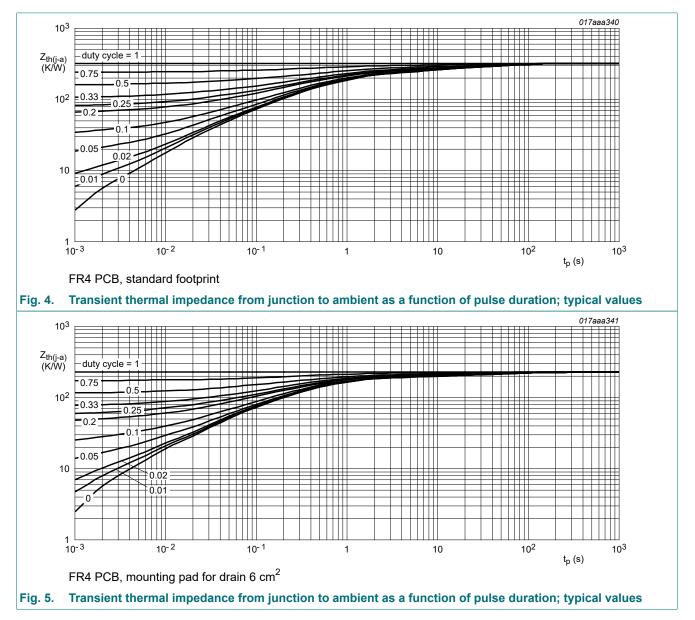
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## 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from	in free air	[1]	-	325	370	K/W
	junction to ambient		[2]	-	230	260	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	50	60	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

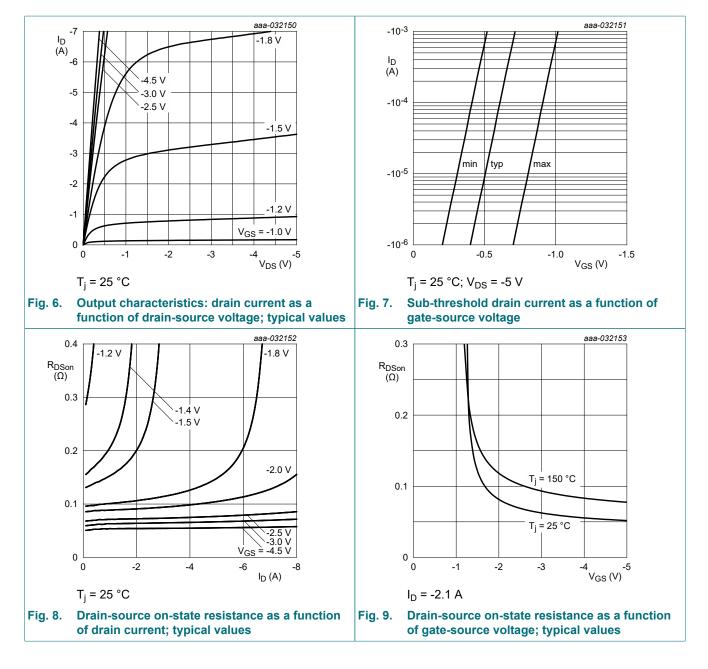


## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D = -250 \ \mu A; V_{GS} = 0 \ V; T_j = 25 \ ^{\circ}C$	-20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D = -250 \ \mu A; V_{DS} = V_{GS}; T_j = 25 \ ^{\circ}C$	-0.5	-0.7	-1	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = -20 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-100	nA
		V <sub>GS</sub> = 8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	100	nA
R <sub>DSon</sub> drain-source o resistance	drain-source on-state	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -2.1 A; T <sub>j</sub> = 25 °C	-	55	70	mΩ
	resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -2.1 A; T <sub>j</sub> = 150 °C	-	86	110	mΩ
		V <sub>GS</sub> = -2.5 V; I <sub>D</sub> = -1.7 A; T <sub>j</sub> = 25 °C	-	74	100	mΩ
		V <sub>GS</sub> = -1.8 V; I <sub>D</sub> = -1.4 A; T <sub>j</sub> = 25 °C	-	101	150	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = -5 V; I <sub>D</sub> = -2.1 A; T <sub>j</sub> = 25 °C	-	6.6	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	8.4	-	Ω
Dynamic ch	naracteristics	· ·				
Q <sub>G(tot)</sub>	total gate charge	$V_{DS} = -10 \text{ V}; \text{ I}_{D} = -2.1 \text{ A}; \text{ V}_{GS} = -4.5 \text{ V};$	-	5.8	8.7	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	0.7	-	nC
Q <sub>GD</sub>	gate-drain charge	1	-	1.8	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = -10 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	458	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	70	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	62	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -10 V; I <sub>D</sub> = -2.1 A; V <sub>GS</sub> = -4.5 V;	-	6	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	13	-	ns
t <sub>d(off)</sub>	turn-off delay time	1	-	46	-	ns
t <sub>f</sub>	fall time	1 –	-	18	-	ns
Source-drai	in diode					
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -0.4 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.7	-1.2	V

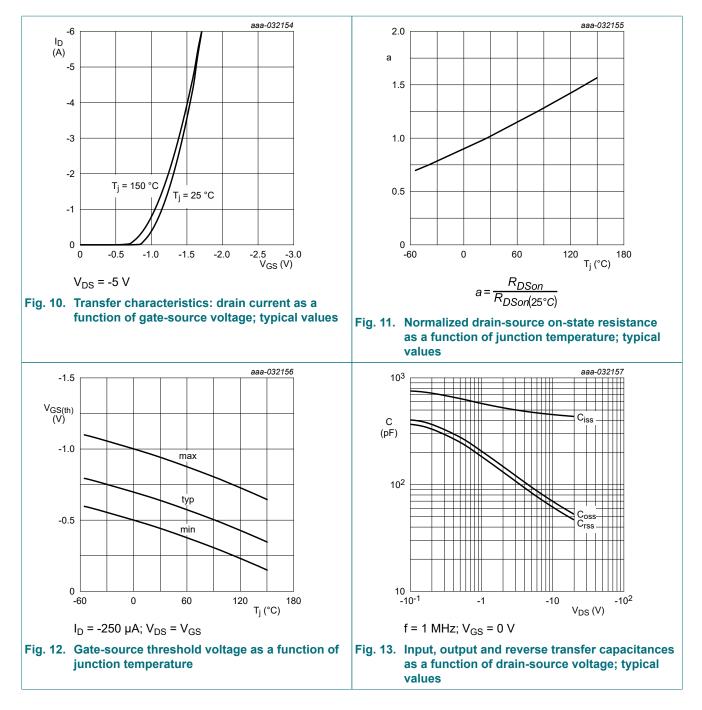
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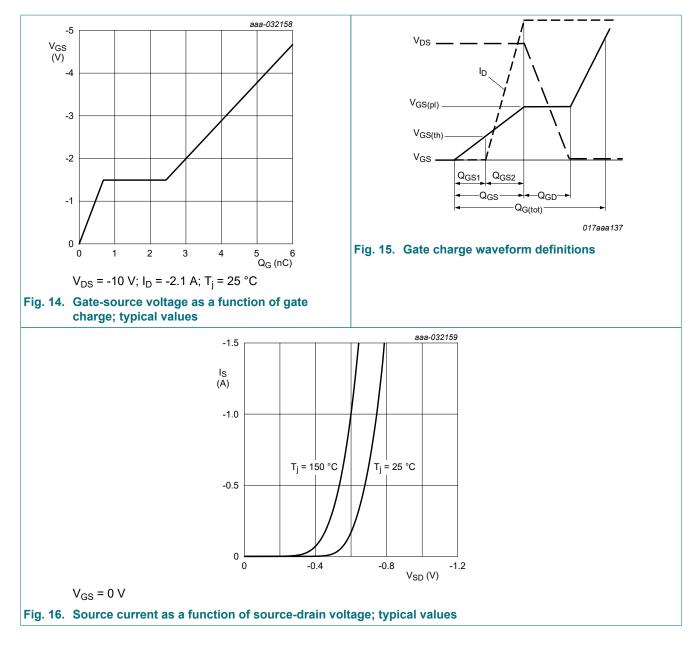
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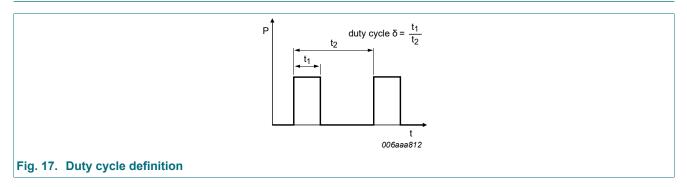
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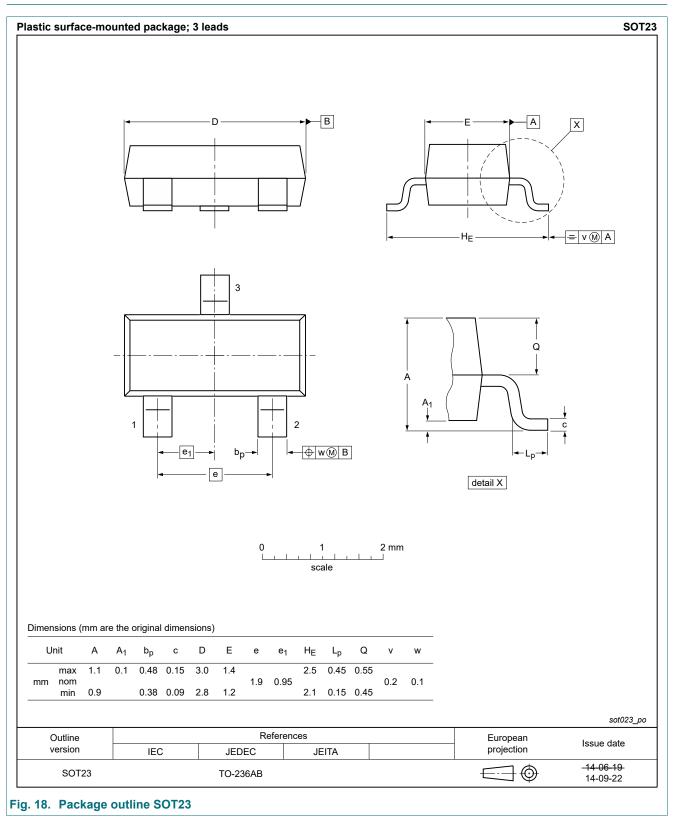


### 11. Test information



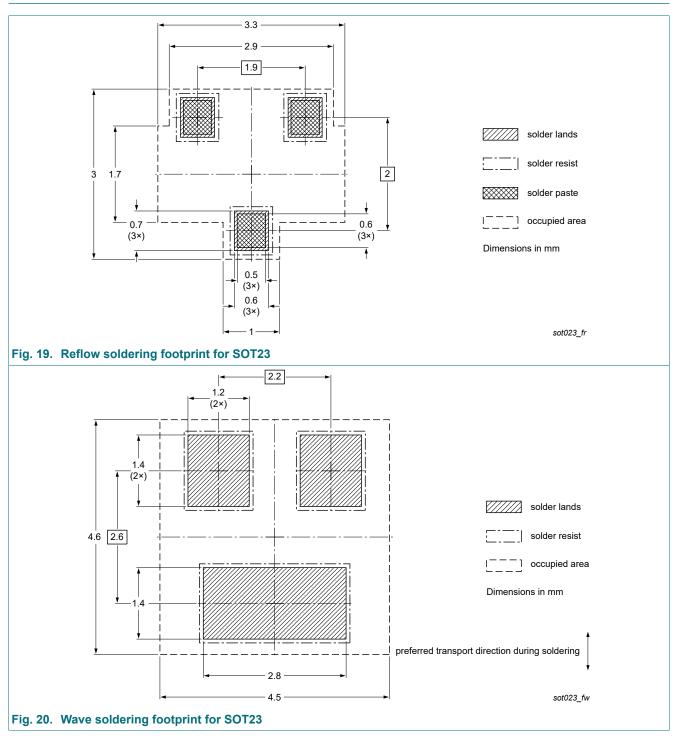
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### 12. Package outline



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### 13. Soldering



### 14. Revision history

### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NXV65UP v.1	20201019	Product	-	-

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## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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